





CMS Simulation Update

February 15, 2024 Geant4 Technical Forum Sunanda Banerjee Vladimir Ivantchenko

Geant4 in Run2 and Run-3

CCMS undergrade to the second second

- For Run-2 legacy MC production
 - Geant4 10.4.p03 + private patches is used
 - VecGeom was used for the first time

• For Run-3 in 2022-2023

- The production platform slc7_amd64_gcc10
- Geant4 10.7.2 + private patches
- VecGeom 1.1.17
- DD4hep 1.19
- CLHEP 2.4.5.1

• For Run-3 2024

- The production platform el8_amd64_gcc12
- Geant4 11.1.2 and enabled features:
 - G4GammaGeneralProcess
 - Extra cut on photo-effect is enabled
 - G4TransportationWithMsc
 - LTO method to build executable
- DD4hep 1.27.2
- VecGeom 1.2.7
- CLHEP 2.4.7.1
- Currently on validation
 - Geant4 11.2
 - The 1st patch to 11.2 will be tested promptly



CPU performance of CMS production

Ratio of Run3/Run2 CPU per event for different WFs	QCD	Z->e+e-	ttbar	T1tttt
2022-2023 GEN-SIM production	0.70	0.75	0.79	0.83
2024 GEN-SIM production	0.62	0.71	0.71	0.74

- T1tttt is pp \rightarrow gluino + gluino, gluino \rightarrow ttbar + lightest neutralino
- Significant speed-up came from
 - Geant4 version
 - Computing platform
 - LTO method

Phase-2 simulation preparations (1/2)

New detectors

- Tracker -
- MTD precise timing
- HGCal endcap calorimeter
- Extra muon chambers
- PPS and beam monitors
- Geometry description is in progress
 - GDML file for the current variant of geometry D98 is available







Phase-2 simulation preparations (2/2)

- Geant4 configuration nearly the same as for Run-3
 - Physics List FTFP_BERT_EMM is used
 - Slow down of Phase-2 versus Run-3 about factor 2
 - Mainly due to the HGCal calorimeter
- R&D is in progress
 - G4HepEM external library is integrated into CMSSW
 - May be enabled via alternative Physics List
 - Celeritas external library is integrated into CMSSW
 - Not yet possible to enable

Both Endcaps	Silicon	Scintillator	
Area	~620 m ²	~370 m²	/m
Channel Size	0.5 - 1.2 cm ²	4 - 30 cm ²	
# Channels	~6 M	~240 k	
# Modules	~27000	~4000	Constitut
Op. Temp.	-30 C	-30 C	Scintilia
Per Endcap	CE-E	CE-H Si Si+Scint	
Absorber	Pb, CuW, Cu	Stainless steel, Cu	Silleon
Depth	27.7 X ₀	10 λ	CE-H
Layers	26	7 14	CEFE
Weight	23 t	205 t	

We would like to thanks Geant4 team for effective resolution of problems connected both with Run-3 simulation and R&D efforts

Thank you